



General Description

Polyfet's GAN (on SiC) HEMT power transistors contain no internal matching; making them suitable for both broadband and narrow band applications. The use of a thermally enhanced package enables this device to have superior heat dissipation properties. The high drain break down voltage permits this device to operate over a wide voltage range.



RF POWER GAN TRANSISTOR
 80.0 Watts Single Ended
 Package Style GX
HIGH EFFICIENCY, LINEAR
HIGH GAIN, LOW NOISE
ROHS COMPLIANT

ABSOLUTE MAXIMUM RATINGS (T = 25 °C)

Total Device Dissipation	Junction to Case Thermal Resistance	Maximum Junction Temperature	Storage Temperature	Drain to Source Voltage	Gate to Source Voltage
95 Watts	3.00 °C/W	200 °C	-65 °C to 150 °C	180 V	-10 V to + 2 V

RF CHARACTERISTICS (80.0 WATTS OUTPUT)

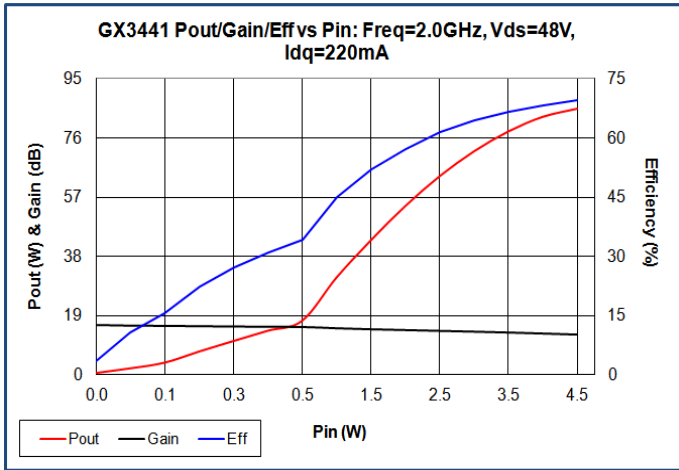
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Gps	Common Source Power Gain	12			dB	Idq = 0.22 A, Vds = 48.0 V, F = 2,000 MHz
η	Drain Efficiency		60		%	Idq = 0.22 A, Vds = 48.0 V, F = 2,000 MHz
VSWR	Load Mismatch Tolerance			10:1	Relative	Idq = 0.22 A, Vds = 48.0 V, F = 2,000 MHz

ELECTRICAL CHARACTERISTICS (EACH SIDE)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Bvdss	Drain Breakdown Voltage	250			V	Ids = 10.00mA, Vgs = -8V
Idsat	Saturation Current		8.00		Amp	Vgs = +2V, Vds = 10V
Idss	Zero Bias Drain Current			3.0	mA	Vds = 48.0 V, Vgs = -8V
Vgs	Gate Bias for Drain Current		-2.5		V	Vds = 48.0 V Ids = 0.22A
Ciss	Common Source Input Capacitance		9.2		pF	Vds = 48.0 Vgs = -8V, F = 1 MHz
Crss	Common Source Feedback Capacitance		0.40		pF	Vds = 48.0 Vgs = -8V, F = 1 MHz
Coss	Common Source Output Capacitance		6.0		pF	Vds = 48.0 Vgs = -8V, F = 1 MHz

GX3441

POUT VS PIN GRAPH



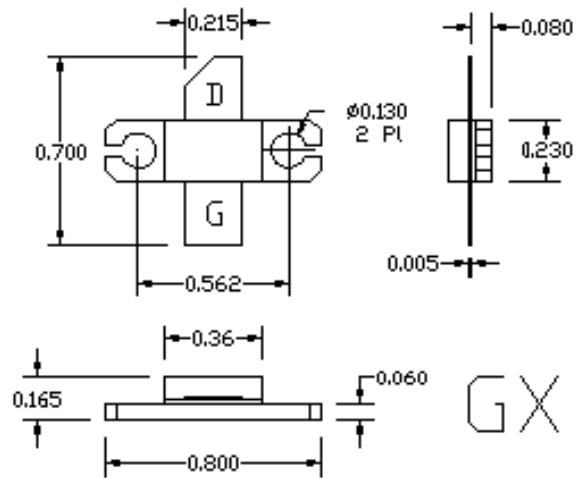
BROADBAND PERFORMANCE

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PACKAGE DIMENSIONS IN INCHES



Tolerance .XX +/-0.01 .XXX +/- .005 inches

POLYFET RF DEVICES

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1110 Avenida Acaso, Camarillo, Ca 93012 Tel:(805) 484-4210 FAX: (805) 484-3393 EMAIL:Sell@polyfet.com URL:www.polyfet.com